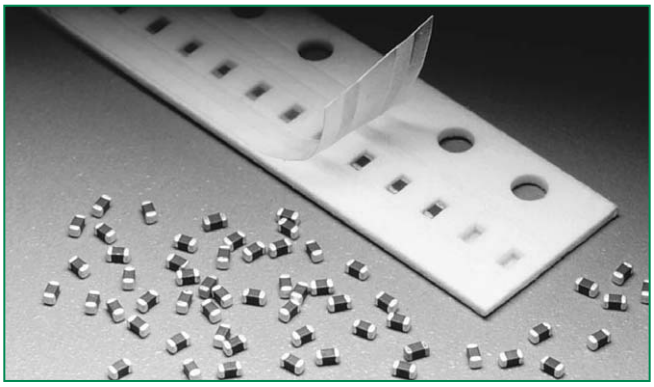
RoHS MHS Varistor Series



Size Table

Metric	EIA
1005	0402
1608	0603

Description

The Multilayer High-Speed MHS Series is a very-low capacitance extension to the Littelfuse ML family of Transient Voltage Surge Suppression devices available in an 0402 and 0603-size surface mount chip.

The MHS series provides protection from ESD and EFT in high-speed data-line and other high frequency applications. The low capacitance of the MHS Series permits usage in analog or digital circuits where it will not attenuate or distort the desired signal or data.

Their small size is ideal for high-density printed circuit boards, being typically applied to protect intergrated circuits and other sensitive components. They are particularly well suited to suppress ESD events including those specified in IEC 61000-4-2 or other standards used for ElectroMagnetic Compliance (EMC) testing.

The MHS series is manufactured from semiconducting ceramics and is supplied in a leadless, surface mount package. The MHS Series is also compatible with modern reflow and wave soldering prcesses.

Littelfuse Inc. manufactures other Multilayer Varistor Series products, see the ML, MLE, MLN and AUML series data sheets.

Applications

- Data, Diagnostic I/O Ports
- Universal Serial Bus (USB)
- Video & Audio Ports
- Portable/Hand-Held Products
- Mobile Communications
- Computer/DSP Products
- Industrial Instruments Including Medical

Features

- RoHS Compliant
- 3pF, 12pF, and 22pF Capacitance Versions Suitable for High Speed Data-Rate Lines
- ESD Rated to IEC 61000-4-2 (Level 4)
- EFT/B Rated to IEC 61000-4-4 (Level 4)
- Low Leakage Currents
- -55°C to + 125°C Operating Temperature Range
- Inherently Bi-directional

Absolute Maximum Ratings

- For ratings of individual members of a series, see device ratings and specifications table.

Continuous	MHS Series	Units
Steady State Applied Voltage:		
DC Voltage Range ($V_{M(DC)}$) : V0402/0603MHS03	≤ 42	V
V0402/0603MHS12	≤ 18	V
V0402/0603MHS22	≤ 09	V
Operating Ambient Temperature Range (T_A)	-55 to + 125	°C
Storage Temperature Range (T_{STG})	-55 to + 150	°C

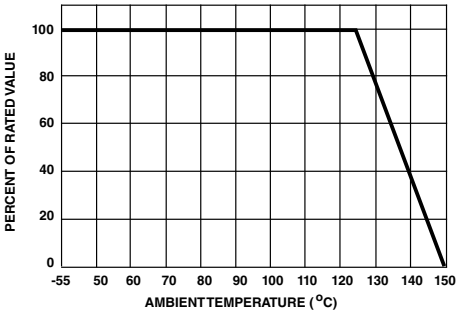
Device Ratings and Specifications

Part Number	Performance Specifications (25 °C)							
	Maximum Clamping Voltage At 1A (8X20µs)	Maximum ESD Clamp Voltage (Note 1)		Typical Leakage Current at Specified DC Voltage		Typical Capacitance at 1MHz (1V p-p)		Typical Inductance (from Impedance Analysis)
		8kV Contact (Note 2)	15kV AIR (Note 3)	3.5V	5.5V	C (Note 4)		L
		Clamp	Clamp	P	I_L	MIN	MAX	
	(V_c)	(V)	(V)	(µA)	(µA)	(pF)	(pF)	(nH)
V0402MHS03N	135	<300	<400	0.5	1.00	1	6 (Note 5)	<1.0
V0603MHS03N	135	<300	<400	0.5	1.00	1	6	<1.0
V0402MHS12N	55	<125	<160	0.5	1.00	8	16	<1.0
V0603MHS12N	55	<125	<160	0.5	1.00	8	16	<1.0
V0402MHS22N	30	<125	<160	0.5	1.00	15	29	<1.0
V0603MHS22N	30	<65	<100	0.5	1.00	15	29	<1.0

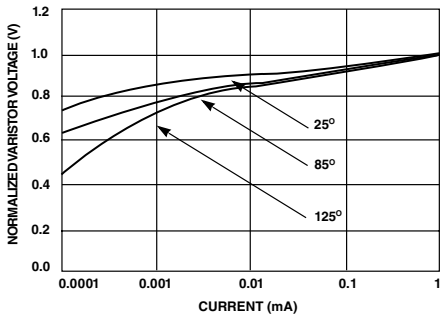
NOTES:
1. Tested to IEC-61000-4-2 Human Body Model (HBM) discharge test circuit.
2. Direct discharge to device terminals (IEC preferred test method).
3. Corona discharge through air (represents actual ESD event).
4. Capacitance may be customized, contact your Littelfuse Sales Representative.
5. V0402MHS03 available with Min: 2pF, Max 5pF as 'R' packing option, i.e. V0402MHS03NR.

Peak Current and Energy Derating Curve

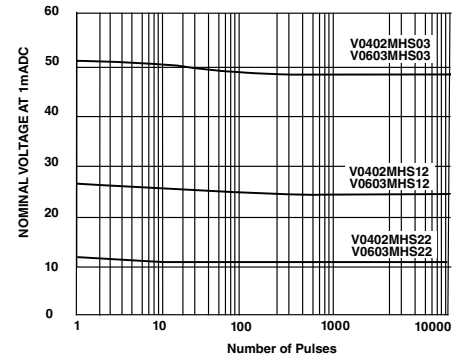
For applications exceeding 125°C ambient temperature, the peak surge current and energy ratings must be reduced as shown below.



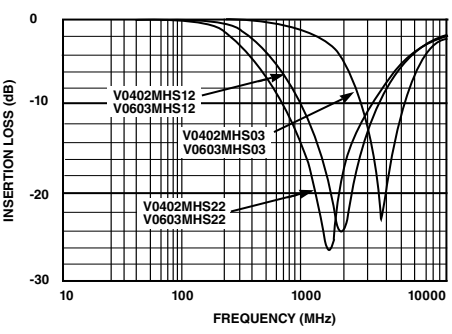
Standby Current at Normalized Varistor Voltage and Temperature



Nominal Voltage Stability to Multiple ESD Impulses (8kV Contact Discharges per LEC 61000-4-2)



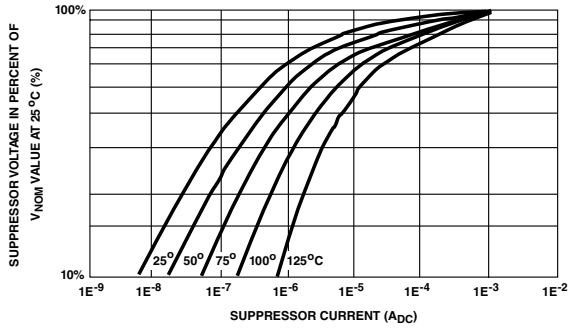
Insertion Loss (S21) Characteristics



Device Characteristics

At low current levels, the V-I curve of the multilayer transient voltage suppressor approaches a linear (ohmic) relationship and shows a temperature dependent effect. At or below the maximum working voltage, the suppressor is in a high resistance modex (approaching $10^6\Omega$ at its maximum rated working voltage). Leakage currents at maximum rated voltage are below 100µA, typically 25µA; for 0402 size below 20µA, typically 5µA.

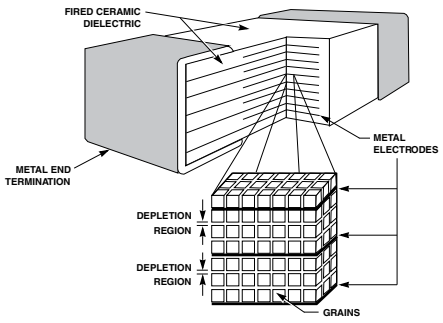
Typical Temperature Dependance of the Haracteristic Curve in the Leakage Region



Speed of Response

The Multilayer Suppressor is a leadless device. Its response time is not limited by the parasitic lead inductances found in other surface mount packages. The response time of the Zinc Oxide dielectric material is less than 1 nanosecond and the MLE can clamp very fast dV/dT events such as ESD. Additionally, in "real world" applications, the associated circuit wiring is often the greatest factor effecting speed of response. Therefore, transient suppressor placement within a circuit can be considered important in certain instances.

Multilayer Internal Construction



Lead (Pb) Soldering Recommendations

The principal techniques used for the soldering of components in surface mount technology are IR Re-flow & Wave soldering. Typical profiles are shown on the right.

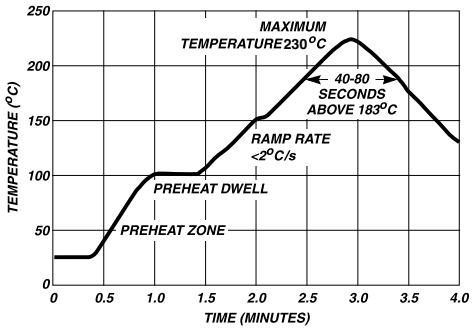
The recommended solder for the MHS suppressor is a 62/36/2 (Sn/Pb/Ag), 60/40 (Sn/Pb) or 63/37 (Sn/Pb). Littelfuse also recommends an RMA solder flux.

Wave soldering is the most strenuous of the processes. To avoid the possibility of generating stresses due to thermal shock, a preheat stage in the soldering process is recommended, and the peak temperature of the solder process should be rigidly controlled.

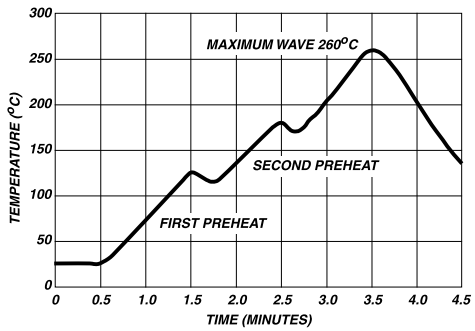
When using a reflow process, care should be taken to ensure that the MHS chip is not subjected to a thermal gradient steeper than 4 degrees per second; the ideal gradient being 2 degrees per second. During the soldering process, preheating to within 100 degrees of the solderís peak temperature is essential to minimize thermal shock.

Once the soldering process has been completed, it is still necessary to ensure that any further thermal shocks are avoided. One possible cause of thermal shock is hot printed circuit boards being removed from the solder process and subjected to cleaning solvents at room temperature. The boards must be allowed to cool gradually to less than 50˚C before cleaning.

Reflow Solder Profile



Wave Solder Profile



Lead-free (Pb-free) Soldering Recommendations

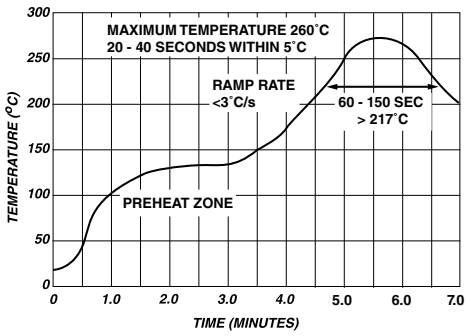
Littelfuse offers the Nickel-Barrier termination finish for the optimum Pb-free solder performance.

The preferred solder is 96.5/3.0/0.5 (SnAgCu) with an RMA flux, but there is a wide selection of pastes & fluxes available with which the nickel barrier parts should be compatible.

The reflow profile must be constrained by the maximums in the Lead-free Reflow Profile. For Pb-free Wave soldering, the Wave Solder Profile still applies.

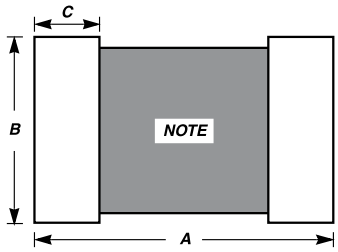
Note: the Pb-free paste, flux & profile were used for evaluation purposes by Littelfuse, based upon industry standards & practices. There are multiple choices of all three available, it is advised that the customer explores the optimum combination for their process as processes vary considerably from site to site.

Lead-free Re-flow Profile



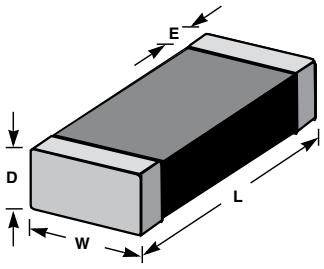
Dimensions

PAD LAYOUT DEMENSIONS



Note: Avoid metal runs in this area, parts are not recommended for use in applications using silver (Ag) expoxy paste.

CHIP LAYOUT DIMENSIONS



Dimension	0402 Size		0603 Size	
	IN	MM	IN	MM
A	0.067	1.700	0.100	2.540
B	0.020	0.510	0.030	0.760
C	0.024	0.610	0.035	0.890
D Max.	0.024	0.600	0.040	1.000
E	0.10±0.006	0.25±0.15	0.015±0.008	0.4±0.2
L	0.039±0.004	1.00±0.10	0.063±0.006	1.6±0.15
W	0.020±0.004	0.50±0.10	0.032±0.006	0.8±0.15

Part Numbering System

V 0402 MHS 03 N H

DEVICE FAMILY
Littelfuse TVSS Device

DEVICE SIZE
i.e. 40Mil x 20Mil
(1.0mm x 0.5mm)

SERIES DESIGNATOR
Multilayer Hi-Speed

CAPACITANCE DESIGNATION
03 = 3pF
12 = 12pF
22 = 22pF

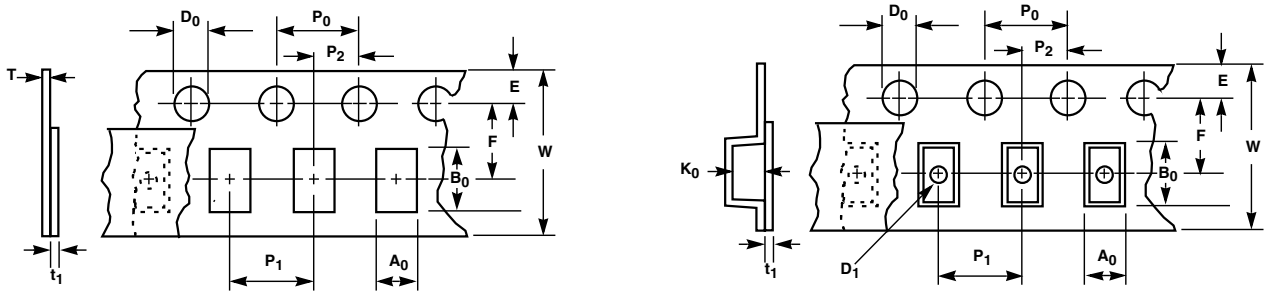
END TERMINATION OPTION
N: Nickel Barrier (Ni/Sn)

PACKING OPTIONS
T: 13in (330mm) Diameter Reel, Plastic Carrier Tape (0603)
H: 7in (178mm) Diameter Reel, Plastic Carrier Tape
R: 7in (178mm) Diameter Reel, Paper Carrier Tape

Packaging

Device Size	13 Inch Reel ("T" Option)	7 Inch Reel ("H" Option)	7 Inch Reel ("R" Option)
0603	10,000	2,500	4,000
0402	N/A	N/A	10,000

Tape and Reel Specifications



Symbol	Description	Dimensions in Millimeters	
		0402 Size	0603 Size
A_0	Width of Cavity	Dependent on Chip Size to Minimize Rotation.	
B_0	Length of Cavity	Dependent on Chip Size to Minimize Rotation.	
K_0	Depth of Cavity	Dependent on Chip Size to Minimize Rotation.	
W	Width of Tape	8±0.2	8±0.3
F	Distance Between Drive Hole Centers and Cavity Centers	3.5±.05	3.5±.05
E	Distance Between Drive Hole Centers and Tape Edge	1.75±0.1	1.75±0.1
P_1	Distance Between Cavity Centers	2±0.05	4±0.1
P_2	Axial Drive Distance Between Drive Hole Centers & Cavity Centers	2±0.1	2±0.1
P_0	Axial Drive Distance Between Drive Hole Centers	4±0.1	4±0.1
D_0	Drive Hole Diameter	1.55±0.05	1.55±0.05
D_1	Diameter of Cavity Piercing	N/A	1.05±0.05
T_1	Top Tape Thickness	0.1 Max	0.1 Max
T	Nominal Carrier Tape Thickness	1.1	1.1

Notes:
- Conforms to EIA-481-1, Revision A
- Can be supplied to IEC publication 286-3